



YOUSHANG SEMICONDUCTOR

设计研发新型功率器件

各类小信号开关

中低压及高压大电流等场效应管

0755-83047638
ysbdt@szyoushang.cn
www.szyoushang.cn



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Features

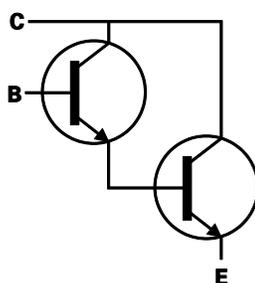
- $BV_{CEO} > 60V$
- Darlington Transistor $h_{FE} > 10k$ @ 100mA for High Gain
- $I_C = 500mA$ High Continuous Collector Current
- Complementary Darlington PNP Type: NK-BCV46

Mechanical Data

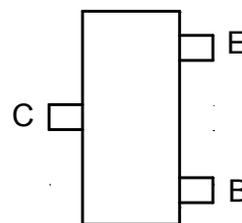
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 
- Weight 0.008 grams (Approximate)



Top View



Device Symbol



Top View
Pin-Out

Absolute Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	80	V
Collector-Emitter Voltage	V_{CEO}	60	V
Emitter-Base Voltage	V_{EBO}	10	V
Continuous Collector Current	I_C	500	mA
Peak Pulse Current	I_{CM}	800	mA
Base Current	I_B	100	mA

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

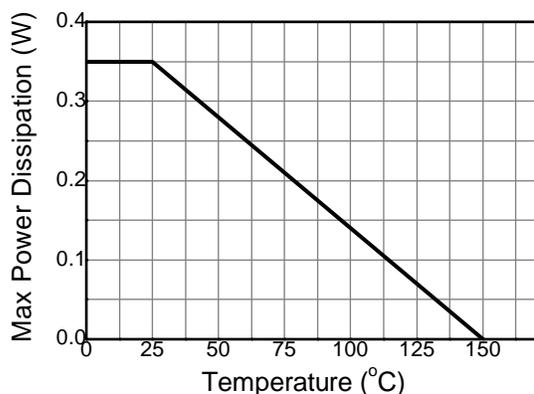
Characteristic	Symbol	Value	Unit
Power Dissipation	P_D	(Note 5) 310	mW
		(Note 6) 350	
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	(Note 5) 403	$^\circ\text{C/W}$
		(Note 6) 357	
Thermal Resistance, Junction to Leads	$R_{\theta JL}$	(Note 7) 350	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

ESD Ratings (Note 8)

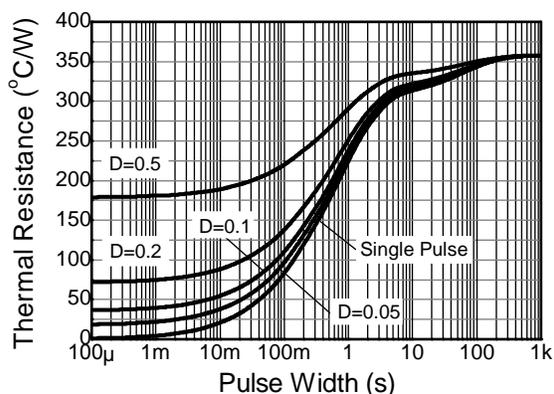
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	2,000	V	2
Electrostatic Discharge - Machine Model	ESD MM	200	V	B

- Notes:
5. For the device mounted on minimum recommended pad layout FR-4 PCB with high coverage of single sided 1oz copper in still air condition; the device is measured when operating in a steady-state condition.
 6. Same as note (6), except the device is mounted on 15mm x 15mm FR-4 PCB.
 7. Thermal resistance from junction to solder-point (at the end of the leads).
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

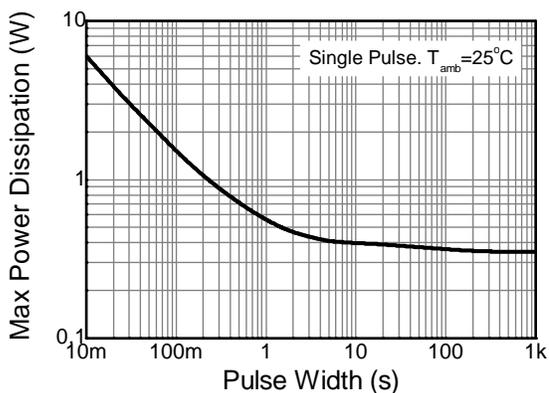
Thermal Characteristics and Derating Information (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Derating Curve



Transient Thermal Impedance



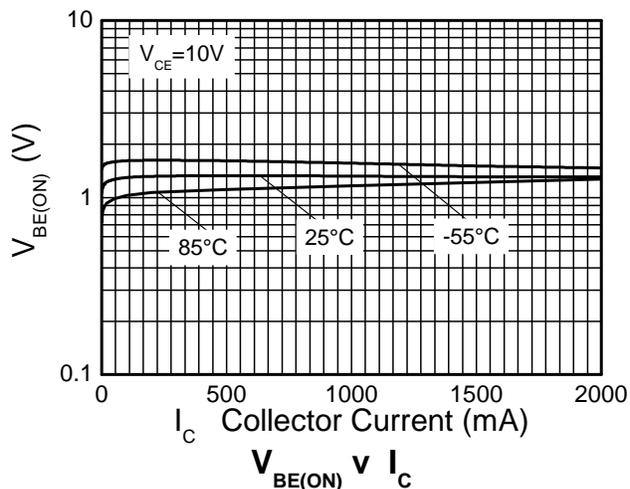
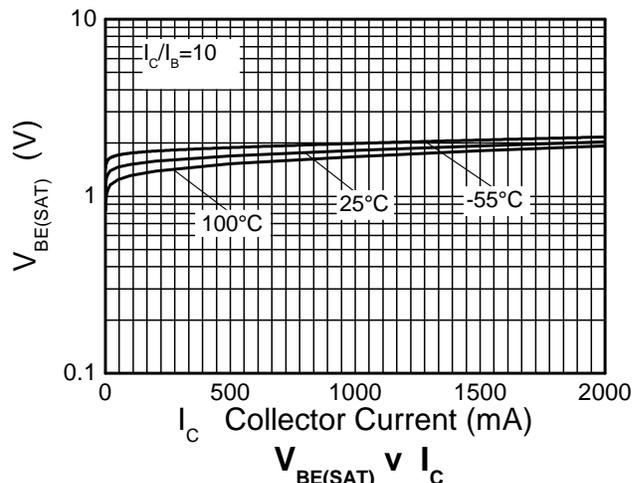
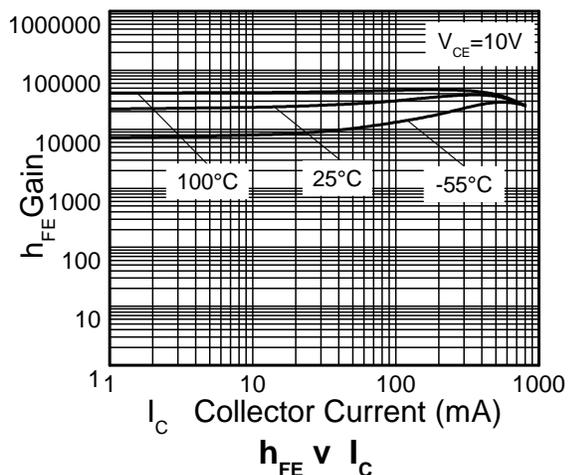
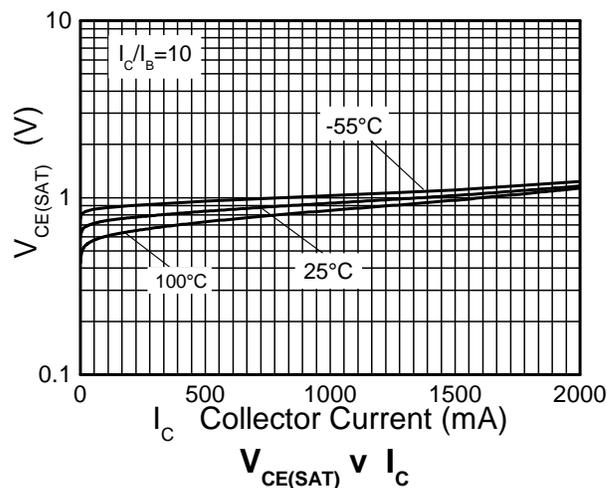
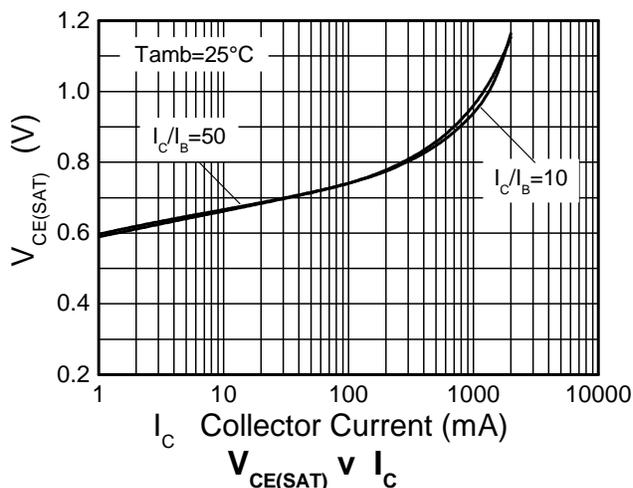
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

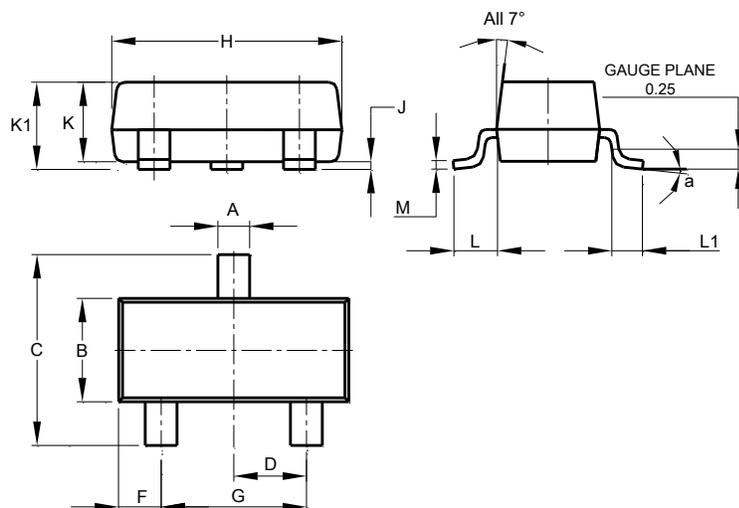
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	80	—	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	60	—	—	V	I _{CEO} = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	10	—	—	V	I _{EBO} = 10μA
Collector Cut-off Current	I _{CBO}	—	<1	100	nA	V _{CB} = 60V
		—	—	10	μA	V _{CB} = 60V, T _A = +150°C
Emitter-base Cut-off Current	I _{EBO}	—	<1	100	nA	V _{EB} = 4V
ON CHARACTERISTICS (Note 9)						
Static Forward Current Transfer Ratio	h _{FE}	2,000 4,000 10,000 2,000	—	—	—	I _C = 100μA, V _{CE} = 1V I _C = 10mA, V _{CE} = 5V I _C = 100mA, V _{CE} = 5V I _C = 500mA, V _{CE} = 5V
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	—	1.0	V	I _C = 100mA, I _B = 0.1mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	—	—	1.5	V	I _C = 100mA, I _B = 0.1mA
SMALL SIGNAL CHARACTERISTICS						
Transition Frequency	f _T	—	170	—	MHz	I _C = 50mA, V _{CE} = 5V, f = 20MHz
Output Capacitance	C _{OBO}	—	3.5	—	pF	V _{CB} = 10V, f = 1MHz

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

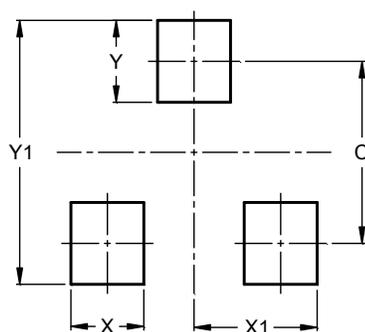


Package Outline Dimensions

SOT23


SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
a	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

SOT23


Dimensions	Value (in mm)
C	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9